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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Li Docket No.: 2003 P 54557 US
Serial No.: 10/771,075 Art Unit: 2811
Filed: February 3, 2004 Examiner: Gene M. Munson
Title: Transistor with Doped Gate Dielectric

Mail Stop: Amendment
Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Dear Sir:

The following amendments and remarks are presented in response to the Examiner's Office Action mailed March 11, 2005. Please amend the above-referenced application as follows.